

10/089479

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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10089479	FILING DATE 03/28/2002	CLASS 438	SUBCLASS 428	CAU 2812	EXAMINER D. NHU
<p>**APPLICANTS: Kim Bong-Cheol;</p>					
<p>**CONTINUING DATA VERIFIED: THIS APPLICATION IS A 371 OF PCT/KR00/00935 08/21/2000</p>					
<p>** FOREIGN APPLICATIONS VERIFIED: REPUBLIC OF KOREA 1999-41892 09/30/1999</p>					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input checked="" type="checkbox"/>		RESCIND <input type="checkbox"/>		ATTORNEY DOCKET NO	
Foreign priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no		35 USC 119 c/o - claims met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no		Verified and Acknowledged Examiners's initials	
TITLE : Apparatus and method for forming single crystalline nitride substrate using hydride vapor phase epitaxy and laser beam		A35109 PCT USA			
U.S. DEPT. OF COMMERCE PAT. & TM. PTO-438 (Rev. 12-94)					

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED			
		Assistant Examiner	<table border="1"> <tr> <td>Total Claims</td> <td>Print Claim for O.G.</td> </tr> </table>	Total Claims	Print Claim for O.G.
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ISSUE FEE		Primary Examiner	DRAWING		
Amount Due	Date Paid		<table border="1"> <tr> <td>Sheets Drawg.</td> <td>Figs. Drawg.</td> <td>Print Fig.</td> </tr> </table>	Sheets Drawg.	Figs. Drawg.
Sheets Drawg.	Figs. Drawg.	Print Fig.			
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.	Application Examiner		

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